



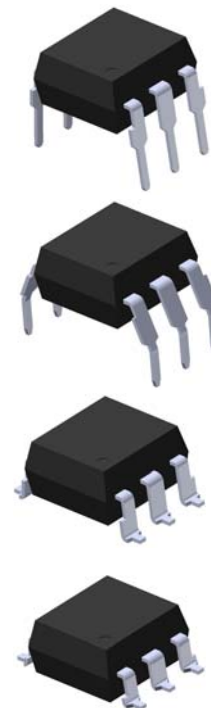
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# 6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

**4N2X Series**  
**4N3X Series**  
**H11AX Series**

## Features:

- 4N2X series: 4N25, 4N26, 4N27, 4N28
- 4N3X series: 4N35, 4N36, 4N37, 4N38
- H11AX series: H11A1, H11A2, H11A3, H11A4, H11A5
- High isolation voltage between input and output  
(Viso=5000 V rms)
- Creepage distance >7.62 mm
- Operating temperature up to +110°C
- Compact dual-in-line package
- Pb free and RoHS compliant.
- UL approved (No. E214129)
- VDE approved (No. 132249)
- SEMKO approved (No. 716108 /No. 716109)
- NEMKO approval (No. P06206747)
- DEMKO approval (No. 313924)
- FIMKO approval (No. FI 22807)
- CSA approved (No.1969132)



## Description

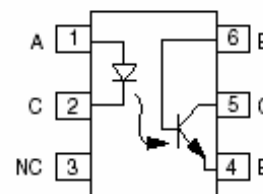
The 4N2X, 4N3X, H11AX series of devices each consist of an infrared emitting diode optically coupled to a phototransistor.

They are packaged in a 6-pin DIP package and available in wide-lead spacing and SMD option.

## Applications

- Power supply regulators
- Digital logic inputs
- Microprocessor inputs

## Schematic



1. Anode
2. Cathode
3. No Connection
4. Emitter
5. Collector
6. Base



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**4N2X Series**  
**4N3X Series**  
**H11AX Series**

## Absolute Maximum Ratings ( $T_a=25^{\circ}\text{C}$ )

| Parameter                                      |  | Symbol    | Rating                 | Unit                   |
|--|--|-----------|------------------------|------------------------|
| Input  | Forward current                                  | $I_F$     | 50                     | mA                     |
|  | Peak forward current ( $t = 10\mu\text{s}$ )     | $I_{FM}$  | 1                      | A                      |
|  | Reverse voltage                                  | $V_R$     | 6                      | V                      |
|  | Power dissipation ( $T_A = 25^{\circ}\text{C}$ ) | $P_D$     | 70                     | mW                     |
|  | Derating factor (above $100^{\circ}\text{C}$ )   |           | 3.8                    | mW/ $^{\circ}\text{C}$ |
| Output   | Collector-Emitter voltage                        | $V_{CEO}$ | 80                     | V                      |
|  | Collector-Base voltage                           | $V_{CBO}$ | 80                     | V                      |
|  | Emitter-Collector voltage                        | $V_{ECO}$ | 7                      | V                      |
|  | Emitter-Base voltage                             | $V_{EBO}$ | 7                      | V                      |
|  | Power dissipation ( $T_A = 25^{\circ}\text{C}$ ) | $P_C$     | 150                    | mW                     |
| Derating factor (above $100^{\circ}\text{C}$ ) | 9.0  |           | mW/ $^{\circ}\text{C}$ |                        |
| Total power dissipation                        |  | $P_{tot}$ | 200                    | mW                     |
| Isolation voltage <sup>*1</sup>                |  | $V_{iso}$ | 5000                   | V <sub>rms</sub>       |
| Operating temperature                          |  | $T_{opr}$ | -55~+110               | $^{\circ}\text{C}$     |
| Storage temperature                            |  | $T_{stg}$ | -55~+125               | $^{\circ}\text{C}$     |
| Soldering temperature <sup>*2</sup>            |  | $T_{sol}$ | 260                    | $^{\circ}\text{C}$     |

### Notes

\*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 & 3 are shorted together, and pins 4, 5 & 6 are shorted together.

\*2 For 10 seconds.



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# 6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

**4N2X Series**  
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**H11AX Series**

## Electrical Characteristics (T<sub>a</sub>=25°C unless specified otherwise)

### Input

| Parameter         | Symbol          | Min. | Typ.* | Max. | Unit | Condition             |
|-------------------|-----------------|------|-------|------|------|-----------------------|
| Forward voltage   | V <sub>F</sub>  | -    | 1.2   | 1.5  | V    | I <sub>F</sub> = 10mA |
| Reverse current   | I <sub>R</sub>  | -    | -     | 10   | μA   | V <sub>R</sub> = 6V   |
| Input capacitance | C <sub>in</sub> | -    | 30    | -    | pF   | V = 0, f = 1MHz       |

### Output

| Parameter                           | Symbol            | Min.             | Typ.* | Max. | Unit | Condition                                  |
|-------------------------------------|-------------------|------------------|-------|------|------|--|
| Collector-Base dark current         | I <sub>CBO</sub>  | -                | -     | 20   | nA   | V <sub>CB</sub> = 10V                      |
| Collector-Emitter dark current      | 4N2X              | I <sub>CEO</sub> | -     | -    | nA   | V <sub>CE</sub> = 10V, I <sub>F</sub> =0mA |
|                                     | H11AX             |                  |       |      |      |  |
|                                     | 4N3X              |                  |       |      |      |  |
| Collector-Emitter breakdown voltage | BV <sub>CEO</sub> | 80               | -     | -    | V    | I <sub>C</sub> =1mA                        |
| Collector-Base breakdown voltage    | BV <sub>CBO</sub> | 80               | -     | -    | V    | I <sub>C</sub> =0.1mA                      |
| Emitter-Collector breakdown voltage | BV <sub>ECO</sub> | 7                | -     | -    | V    | I <sub>E</sub> =0.1mA                      |
| Emitter-Base breakdown voltage      | BV <sub>EBO</sub> | 7                | -     | -    | V    | I <sub>E</sub> =0.1mA                      |
| Collector-Emitter capacitance       | C <sub>CE</sub>   | -                | 8     | -    | pF   | V <sub>CE</sub> =0V, f=1MHz                |

\* Typical values at T<sub>a</sub> = 25°C



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# 6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

**4N2X Series**  
**4N3X Series**  
**H11AX Series**

Transfer Characteristics ( $T_a=25^\circ\text{C}$  unless specified otherwise)

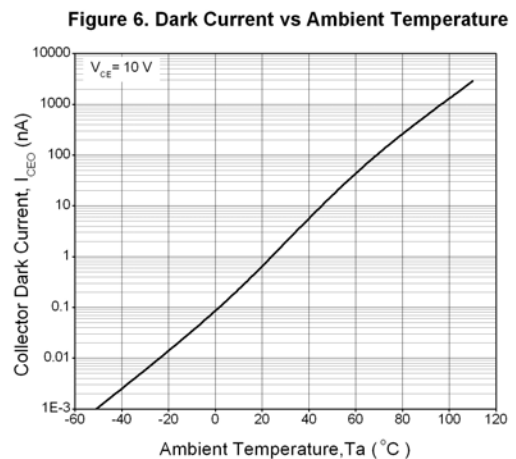
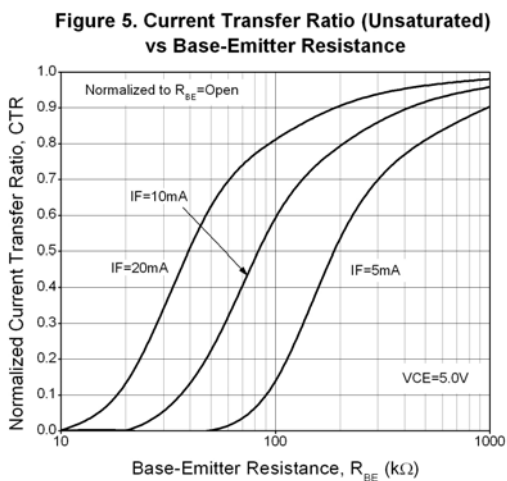
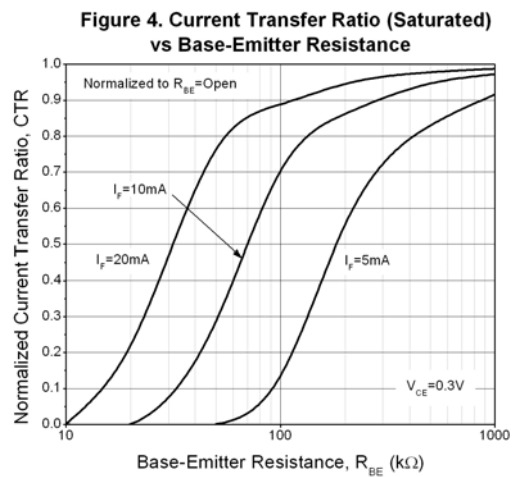
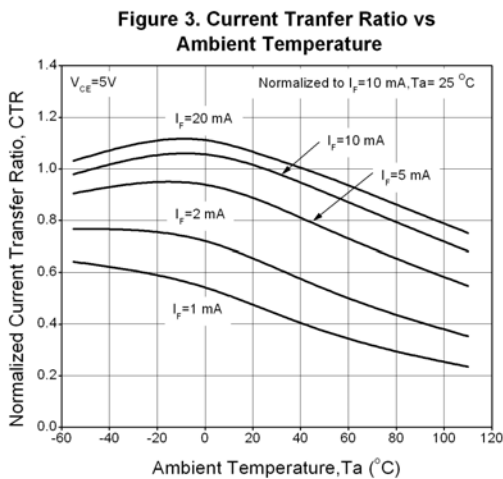
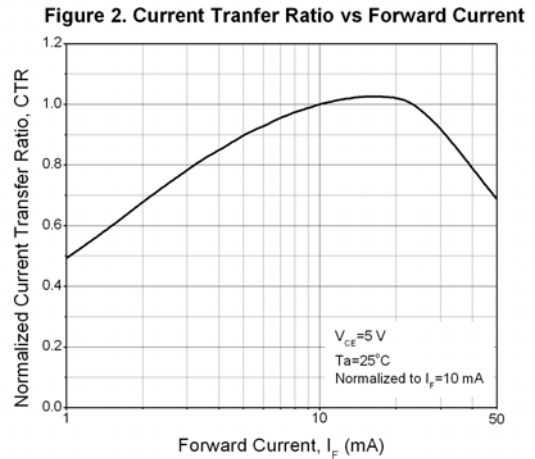
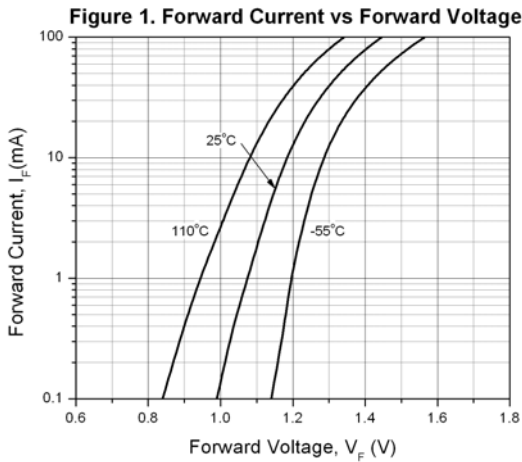
| Parameter                            |   | Symbol        | Min.      | Typ.* | Max. | Unit          | Condition  |
|--------------------------------------|---|---------------|-----------|-------|------|---------------|--|
| Current transfer ratio               | 4N35, 4N36, 4N37  | CTR           | 100       | -     | -    | %             | $I_F = 10\text{mA}, V_{CE} = 10\text{V}$                                 |
|                                      | H11A1   |               | 50        | -     | -    |               |  |
|                                      | H11A5   |               | 30        | -     | -    |               |  |
|                                      | 4N25, 4N26, 4N38, H11A2, H11A3                            |               | 20        | -     | -    |               |  |
|                                      | 4N27, 4N28, H11A4   |               | 10        | -     | -    |               |  |
| Collector-Emitter saturation voltage | 4N25, 4N26, 4N27, 4N28                                    | $V_{CE(sat)}$ | -         | -     | 0.5  | V             | $I_F = 50\text{mA}, I_C = 2\text{mA}$                                    |
|                                      | 4N35, 4N36, 4N37  |               | -         | -     | 0.3  |               | $I_F = 10\text{mA}, I_C = 0.5\text{mA}$                                  |
|                                      | H11A1, H11A2, H11A3, H11A4, H11A5                         |               | -         | -     | 0.4  |               |  |
|                                      | 4N38  |               | -         | -     | 1.0  |               |  |
| Isolation resistance                 |   | $R_{IO}$      | $10^{11}$ | -     | -    | $\Omega$      | $V_{IO} = 500\text{Vdc}$   |
| Input-output capacitance             |   | $C_{IO}$      | -         | 0.2   | -    | pF            | $V_{IO} = 0, f = 1\text{MHz}$  |
| Turn-on time                         | 4N25, 4N26, 4N27, 4N28, H11A1, H11A2, H11A3, H11A4, H11A5 | Ton           | -         | 3     | 10   | $\mu\text{s}$ | $V_{CC} = 10\text{V}, I_F = 10\text{mA}, R_L = 100\Omega$<br>See Fig. 11 |
|                                      | 4N35, 4N36, 4N37, 4N38                                    |               | -         | 10    | 12   |               | $V_{CC} = 10\text{V}, I_C = 2\text{mA}, R_L = 100\Omega$ , See Fig. 11   |
| Turn-off time                        | 4N25, 4N26, 4N27, 4N28, H11A1, H11A2, H11A3, H11A4        | Toff          | -         | 3     | 10   | $\mu\text{s}$ | $V_{CC} = 10\text{V}, I_F = 10\text{mA}, R_L = 100\Omega$<br>See Fig. 11 |
|                                      | 4N35, 4N36, 4N37, 4N38                                    |               | -         | 9     | 12   |               | $V_{CC} = 10\text{V}, I_C = 2\text{mA}, R_L = 100\Omega$ , See Fig. 11   |

\* Typical values at  $T_a = 25^\circ\text{C}$

# 6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

**4N2X Series  
4N3X Series  
H11AX Series**

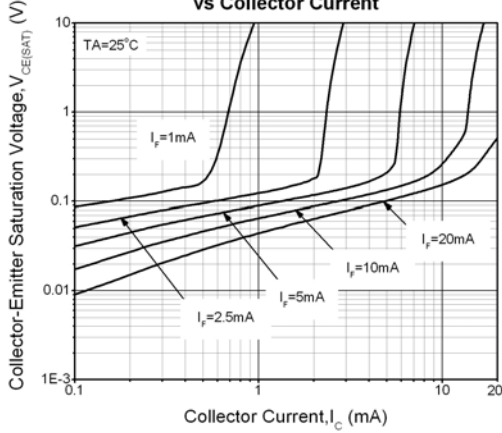
## Typical Performance Curves



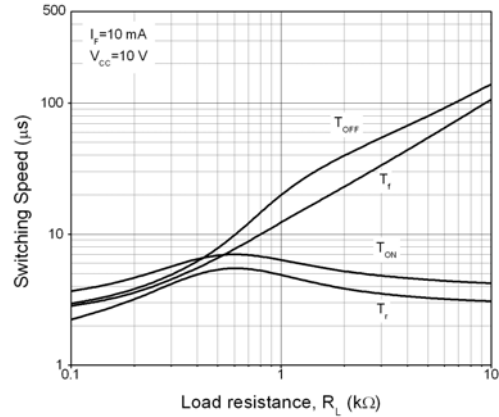
**6 PIN DIP PHOTOTRANSISTOR  
PHOTOCOUPLER**

**4N2X Series  
4N3X Series  
H11AX Series**

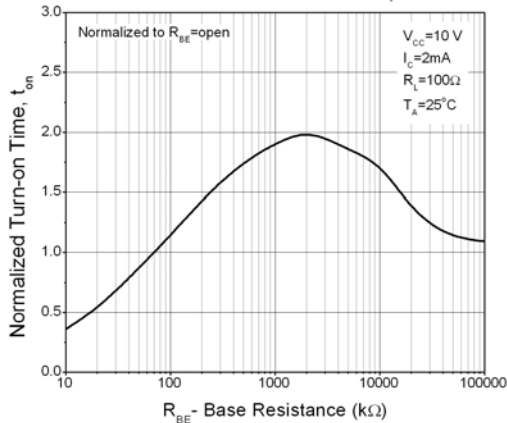
**Figure 7. Collector-Emitter Saturation Voltage vs Collector Current**



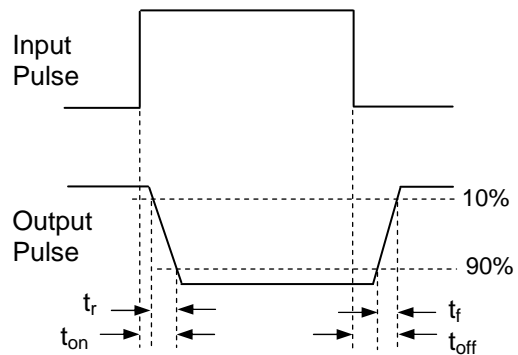
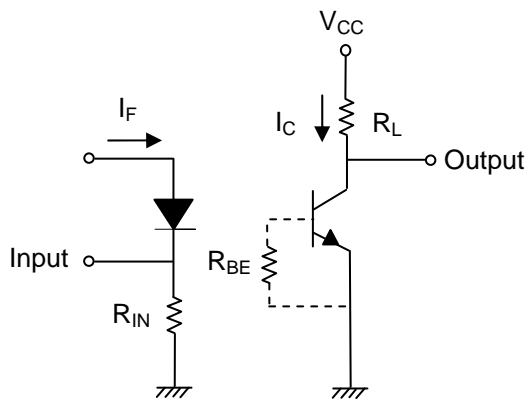
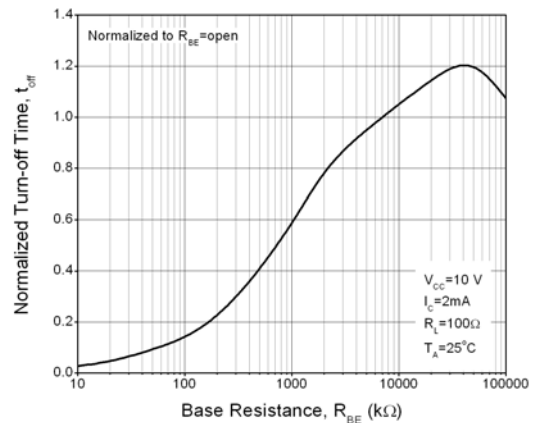
**Figure 8. Switching Time vs Load Resistance**



**Figure 9. Turn-on Time vs Base-Emitter Resistance**



**Figure 10. Turn-off Time vs Base-Emitter Resistance**



**Figure 11. Switching Time Test Circuit & Waveforms**



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# 6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

**4N2X Series**  
**4N3X Series**  
**H11AX Series**

## Order Information

### Part Number

**4NXXY(Z)-V**

or

**H11AXY(Z)-V**

### Note

- XX = Part no. for 4NXX series (25, 26, 27, 28, 35, 36, 37 or 38)
- X = Part no. for H11AX series (1, 2, 3, 4, or 5)
- Y = Lead form option (S, S1, M or none)
- Z = Tape and reel option (TA, TB or none).
- V = VDE (optional)

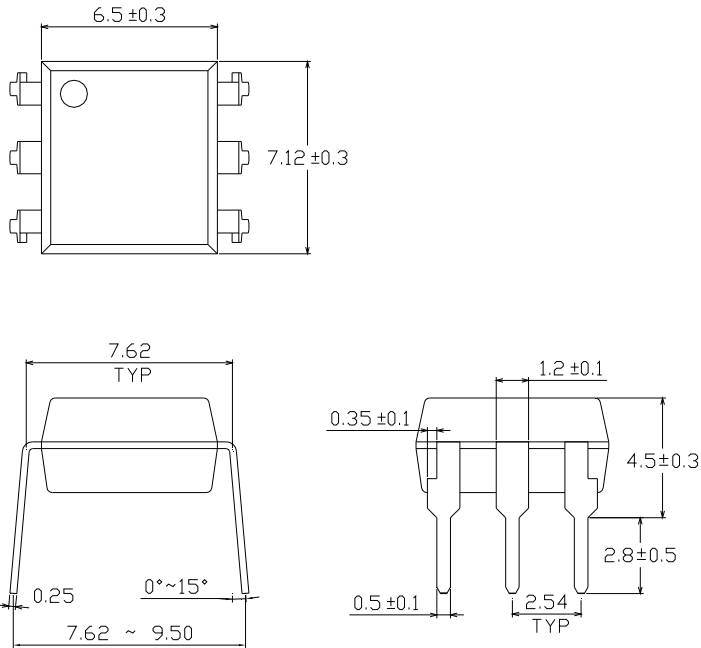
| Option  | Description   | Packing quantity    |
|---------|---|---------------------|
| None    | Standard DIP-6  | 65 units per tube   |
| M       | Wide lead bend (0.4 inch spacing)                             | 65 units per tube   |
| S (TA)  | Surface mount lead form + TA tape & reel option               | 1000 units per reel |
| S (TB)  | Surface mount lead form + TB tape & reel option               | 1000 units per reel |
| S1 (TA) | Surface mount lead form (low profile) + TA tape & reel option | 1000 units per reel |
| S1 (TB) | Surface mount lead form (low profile) + TB tape & reel option | 1000 units per reel |

**6 PIN DIP PHOTOTRANSISTOR  
PHOTOCOUPLER**

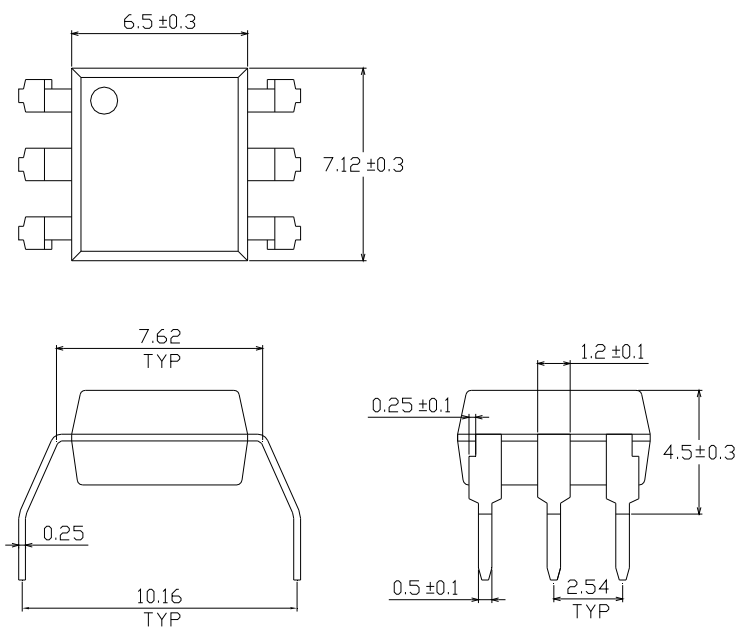
**4N2X Series  
4N3X Series  
H11AX Series**

**Package Drawings  
(Dimensions in mm)**

**Standard DIP Type**



**Option M Type**

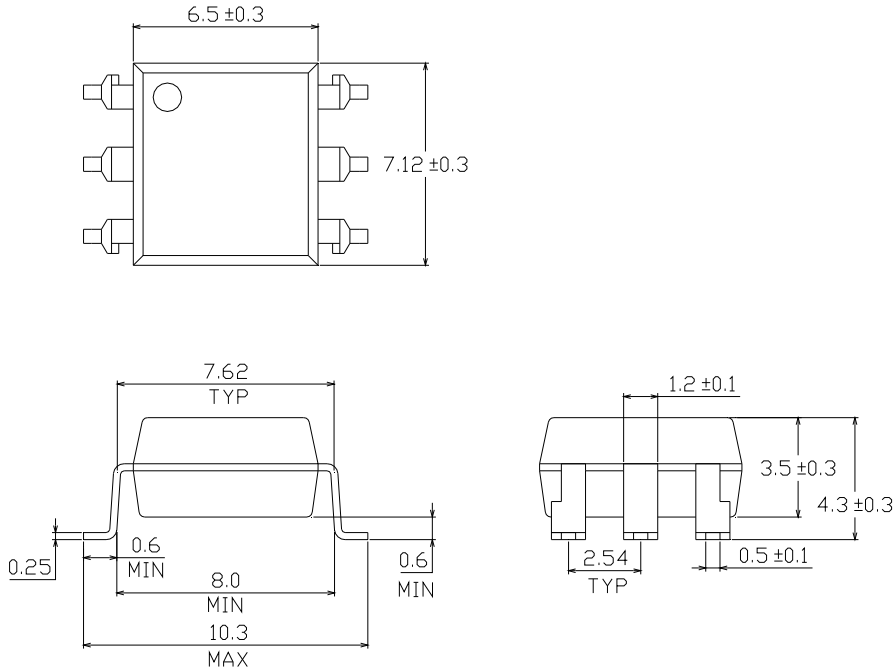




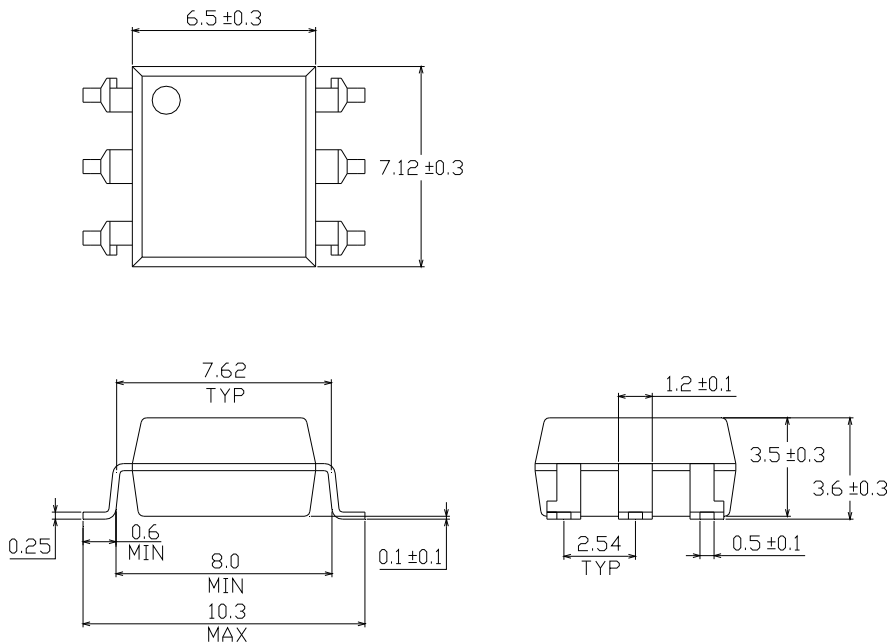
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**4N2X Series  
4N3X Series  
H11AX Series**

**Option S Type**



**Option S1 Type**



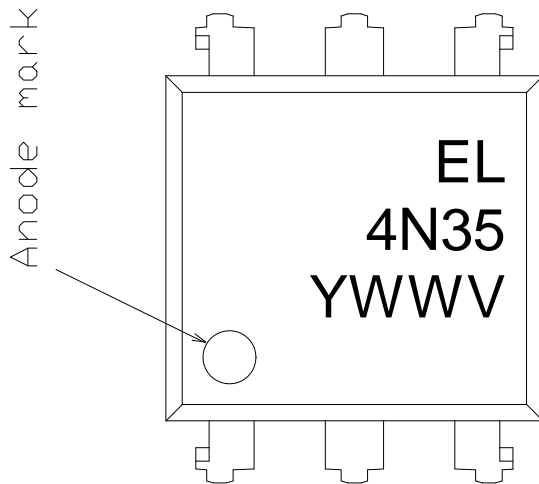
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**4N2X Series  
4N3X Series  
H11AX Series**

Recommended pad layout for surface mount leadform



**Device Marking**



**Notes**

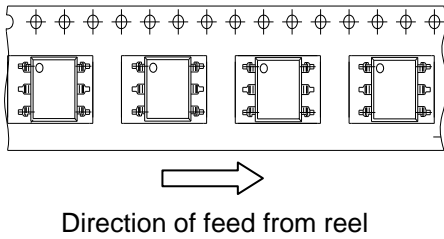
- EL denotes Everlight
- 4N35 denotes Device Number
- Y denotes 1 digit Year code
- WW denotes 2 digit Week code
- V denotes VDE (optional)

**6 PIN DIP PHOTOTRANSISTOR  
PHOTOCOUPLER**

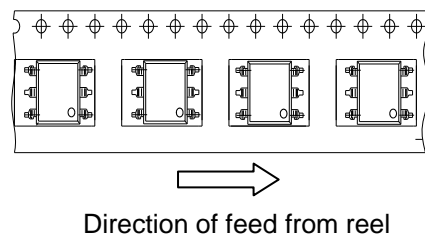
**4N2X Series  
4N3X Series  
H11AX Series**

**Tape & Reel Packing Specifications**

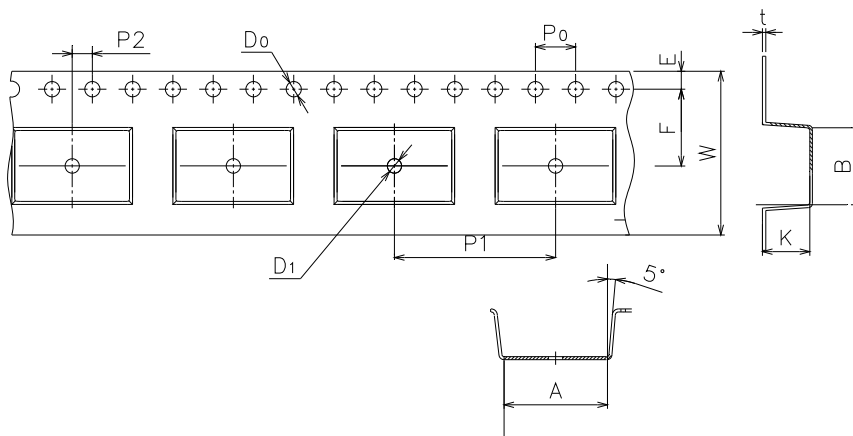
**Option TA**



**Option TB**



**Tape dimensions**



| Dimension No.  | A        | B        | Do      | D1         | E        | F       |
|----------------|----------|----------|---------|------------|----------|---------|
| Dimension (mm) | 10.4±0.1 | 7.52±0.1 | 1.5±0.1 | 1.5+0.1/-0 | 1.75±0.1 | 7.5±0.1 |

| Dimension No.  | Po       | P1       | P2      | t         | W        | K       |
|----------------|----------|----------|---------|-----------|----------|---------|
| Dimension (mm) | 4.0±0.15 | 16.0±0.1 | 2.0±0.1 | 0.35±0.03 | 16.0±0.2 | 4.5±0.1 |

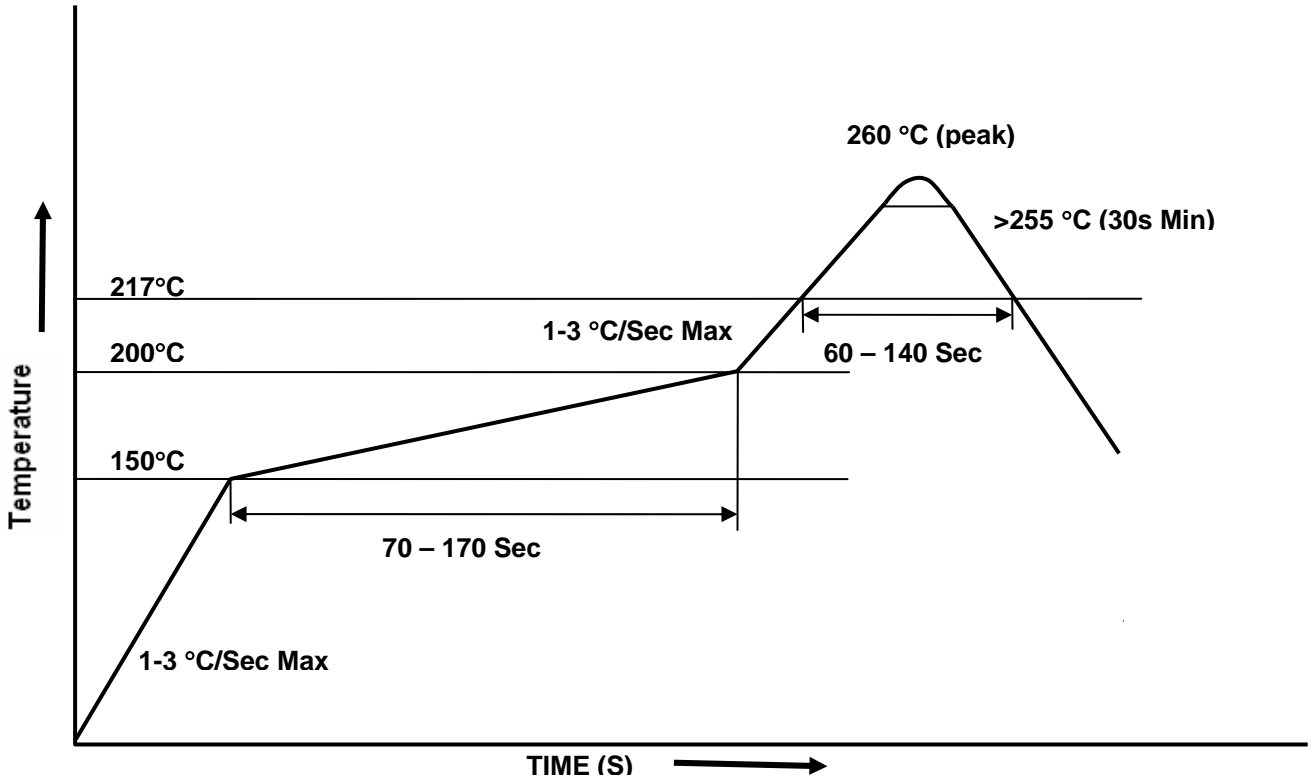


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4N2X Series  
4N3X Series  
H11AX Series

## Solder Reflow Temperature Profile





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## 6 PIN DIP PHOTOTRANSISTOR PHOTOCOUPLER

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**H11AX Series**

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